

SANYO Semiconductors

DATA SHEET

2SC6144SG — NPN Epitaxial Planar Silicon Transistor High-Current Switching Applications

Applications

· Relay drivers, lamp drivers, motor drivers

Features

- · Adoption of MBIT process
- Large current capacitance (IC=10A)
- Low collector-to-emitter saturation voltage (VCE(sat)=180mV(typ.))
- High-speed switching (tf=25ns(typ.))

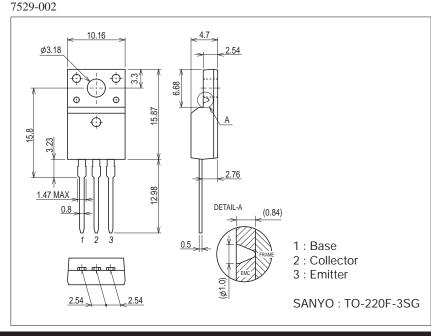
Specifications

Absolute Maximum Ratings at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|------------------------------|------------------|-----------------------------|-------------|------|
| Collector-to-Base Voltage | VCBO | | 60 | V |
| Collector-to-Emitter Voltage | VCEO | | 50 | V |
| Emitter-to-Base Voltage | V _{EBO} | | 5 | V |
| Collector Current | IC | | 10 | А |
| Collector Current (Pulse) | ICP | | 13 | А |
| Base Current | ΙΒ | | 2 | А |
| Collector Dissipation | PC | Tc=25°C, P _T ≤1s | 25 | W |
| Junction Temperature | Tj | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Package Dimensions

unit: mm (typ)



Product & Package Information

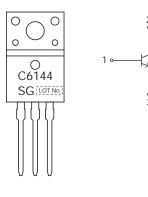
• Package : TO-220F-3SG

• JEITA, JEDEC : SC-67

• Minimum Packing Quantity

: 50 pcs./magazine

Marking Electrical Connection

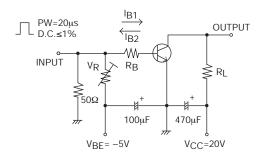


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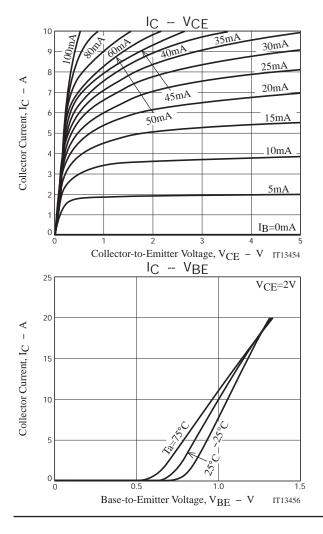
Electrical Characteristics at Ta=25°C

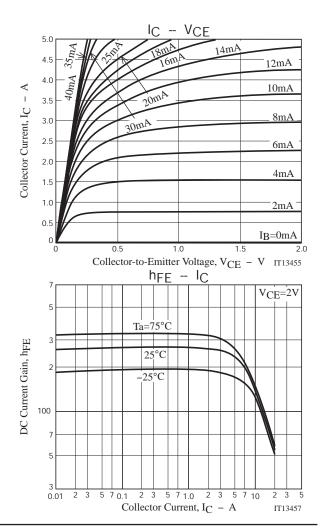
| Parameter | Symbol | Conditions | Ratings | | | Unit |
|---|-----------------------|--|---------|-----|-----|-------|
| | | | min | typ | max | UIIIL |
| Collector Cutoff Current | ICBO | V _{CB} =40V, I _E =0A | | | 10 | μΑ |
| Emitter Cutoff Current | IEBO | V _{EB} =4V, I _C =0A | | | 10 | μΑ |
| DC Current Gain | hFE | V _{CE} =2V, I _C =270mA | 200 | | 560 | |
| Gain-Bandwidth Product | fŢ | V _{CE} =10V, I _C =3A | | 330 | | MHz |
| Output Capacitance | Cob | V _{CB} =10V, f=1MHz | | 60 | | pF |
| Collector-to-Emitter Saturation Voltage | V _{CE} (sat) | IC=6A, IB=300mA | | 180 | 360 | mV |
| Base-to-Emitter Saturation Voltage | V _{BE} (sat) | I _C =6A, I _B =300mA | | | 1.2 | V |
| Collector-to-Base Breakdown Voltage | V(BR)CBO | I _C =100μA, I _E =0A | 60 | | | V |
| Collector-to-Emitter Breakdown Voltage | V(BR)CEO | IC=1mA, RBE=∞ | 50 | | | V |
| Emitter-to-Base Breakdown Voltage | V(BR)EBO | I _E =100μA, I _C =0A | 5 | | | V |
| Turn-On Time | ton | See specified Test Circuit. | | 62 | | ns |
| Storage Time | t _{stg} | See specified Test Circuit. | | 350 | | ns |
| Fall Time | tf | See specified Test Circuit. | | 25 | | ns |

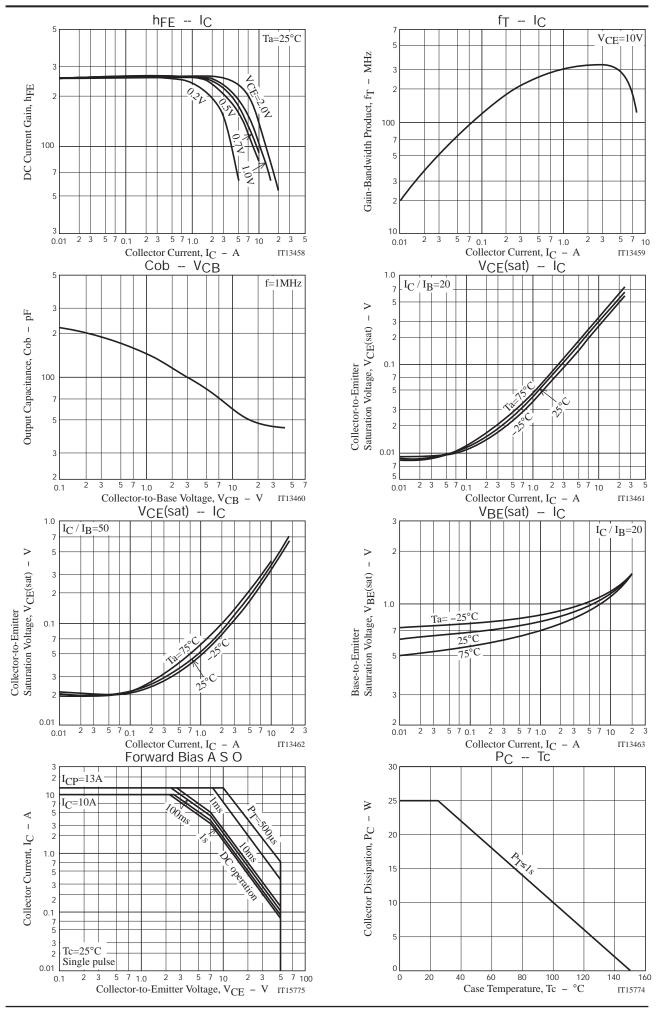
Switching Time Test Circuit



 $I_{C}=20I_{B1}=-20I_{B2}=5A$







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